

# ESDALC14V2-2BP5 ESDALC25-2BP5

## Low capacitance TRANSIL<sup>™</sup> array for ESD protection

## Main applications

Where transient overvoltage protection in ESD sensitive equipment is required, such as :

- Computers
- Printers
- Communication systems such as xDSL modem
- Video equipment

This device is particularly adapted to the protection of symmetrical systems

### Features

- 2 Bidirectional Transil functions
- Breakdown voltage:
  V<sub>BR</sub> = 14.2 V and 25 V minimum
- Low leakage current: < 1 µA
- Low diode capacitance: 14 and 8 pF at 3 V
- Very small PCB area < 2.6 mm<sup>2</sup>

## Description

transients.

The device is ideal for situations where board space saving is required.

## Benefits

- High ESD protection level
- High integration
- Suitable for high density boards



### Order codes

Part Number	Marking
ESDALC14V2-2BP3	A3
ESDALC25-2825	A4

### ESDALCxx-2BP5 Functional diagram



#### Complies with the following standards

#### IEC61000-4-2

Level 4

15 kV (air discharge) 8 kV(contact discharge)

### MIL STD 883E - Method 3015-7 Class 3

25 kV HBM (Human Body Model)

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## 1 Characteristics

Table 1. Absolu	te Ratings (T <sub>amb</sub> = 25°C)
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Symbol	Parameter		Unit
P <sub>PP</sub>	Peak pulse power (8/20 µs) <sup>(1)</sup>		W
Τj	Junction temperature	150	°C
T <sub>stg</sub>	Storage temperature range	-55 to +150	°C
ΤL	Maximum lead temperature for soldering during 10s		°C
T <sub>op</sub>	Operating temperature range <sup>(2)</sup>	-40 to +150	°C

1. For a surge greater than the maximum values, the diode will fail in short circuit

2. The values of the operating parameters versus temperature are given through curves and  $\alpha T$  parameter.

## **1.1** Electrical characteristics (Tamb = 25°C)

Symbol	Parameter		~90.5
V <sub>RM</sub>	Stand-off voltage		× I
$V_{BR}$	Breakdown voltage		
V <sub>CL</sub>	Clamping voltage		
I <sub>RM</sub>	Leakage current	V <sub>CL</sub> V <sub>BR</sub> V <sub>RM</sub>	
I <sub>PP</sub>	Peak pulse current		
αΤ	Voltage temperature coefficient		
V <sub>F</sub>	Forward voltage drop	Slope: 1/Rd	
С	Capacitance		IPP
R <sub>d</sub>	Dynamic resistance		

Pla		V <sub>BR</sub> @ I <sub>R</sub>		I <sub>RM</sub> @ V <sub>RM</sub>		R <sub>d</sub>	αΤ	С	
	Part Numbers	min.	max.		max.		typ.	max.	typ. 3V bias
1050		v	v	mA	μA	v	Ω	10 <sup>-4</sup> /°C	pF
	ESDALC14V2-2BP5	14.2	18	1	1	12	1.5	7	14
	ESDALC25-2BP5	25	29.7	1	1	24	1.3	8	8

# Figure 1. Peak pulse power versus initial junction temperature



# Figure 2. Peak pulse power versus exponential pulse duration









Figure 5. Relative variation of leakage current Figure 6. versus junction temperature (typical values)

ESD response to IEC61000-4-2 (air discharge 15kV, positive surge)



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#### **Ordering information scheme** 2

	ESDA LC XX - 2 B P5
ESD Array	
Low capacitance	
Breakdown voltage	
Number of Transil functions	
<b>Type</b> B = Bidirectional	
Package P5 = SOT665	

#### Package mechanical data 3

#### 3.1 SOT665 package



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In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

4 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
ESDALC14V2-2BP5	A3	SOTees	2 0 mg	3000	
ESDALC25-2BP5	A4	301005	2.9 mg	3000	Tape & Teer

5 Revision history

Date	Revision	Changes
08-Dec-2005	1	First issue

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